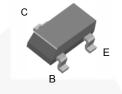


October 2014

FSB560 / FSB560A NPN Low-Saturation Transistor

Features

 These devices are designed with high-current gain and low-saturation voltage with collector currents up to 2 A continuous.



SuperSOTTM-3 (SOT-23)

Ordering Information

Part Number	Marking	Package	Packing Method
FSB560	560	SSOT 3L	Tape and Reel
FSB560A	560A	SSOT 3L	Tape and Reel

Absolute Maximum Ratings(1),(2)

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Values are at $T_A = 25^{\circ}\text{C}$ unless otherwise noted.

Symbol	Parameter	Value	Unit
V _{CEO}	Collector-Emitter Voltage	60	V
V_{CBO}	Collector-Base Voltage	80	V
V _{EBO}	Emitter-Base Voltage	5	V
I _C	Collector Current - Continuous	2	Α
T _J , T _{STG}	Operating and Storage Junction Temperature Range	-55 to +150	°C

Notes:

- 1. These ratings are based on a maximum junction temperature of 150°C.
- 2. These are steady-state limits. Fairchild Semiconductor should be consulted on applications involving pulsed or low-duty-cycle operations.

Thermal Characteristics(3)

Values are at $T_A = 25^{\circ}C$ unless otherwise noted.

Symbol	Parameter	Max.	Unit
В	Total Device Dissipation	500	mW
P _D	Derate Above 25°C	4	mW/°C
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient	250	°C/W

Note:

3. PCB size: FR-4, 76 mm x 114 mm x 1.57 mm (3.0 inch x 4.5 inch x 0.062 inch) with minimum land pattern size.

Electrical Characteristics

Values are at T_A = 25°C unless otherwise noted.

Symbol	Parameter	Conditions		Min.	Max.	Unit
BV _{CEO}	Collector-Emitter Breakdown Voltage	I _C = 10 mA, I _B = 0		60		V
BV _{CBO}	Collector-Base Breakdown Voltage	$I_C = 100 \mu A, I_E = 0$		80		V
BV _{EBO}	Emitter-Base Breakdown Voltage	I _E = 100 μA, I _C = 0		5		V
	Collector Cut-Off Current	V _{CB} = 30 V, I _E = 0			100	nA
I _{CBO}		V _{CB} = 30 V, I _E = 0, T _A = 100°C			10	μΑ
I _{EBO}	Emitter Cut-Off Current	$V_{EB} = 4 \text{ V}, I_{C} = 0$			100	nA
	DC Current Gain ⁽⁴⁾	I _C = 100 mA, V _{CE} = 2 V		70		
		I _C = 500 mA, V _{CE} = 2 V	FSB560	100	300	
h _{FE}			FSB560A	250	550	
		I _C = 1 A, V _{CE} = 2 V		80		
		I _C = 2 A, V _{CE} = 2 V		40		
		I _C = 1 A, I _B = 100 mA			300	
V _{CE} (sat)	Collector-Emitter Saturation Voltage ⁽⁴⁾	$I_{\rm C} = 2 \text{A}, I_{\rm B} = 200 \text{mA}$	FSB560		350	mV
			FSB560A		300	
V _{BE} (sat)	Base-Emitter Saturation Voltage ⁽⁴⁾	I _C = 1 A, I _B = 100 mA		/	1.25	V
V _{BE} (on)	Base-Emitter On Voltage ⁽⁴⁾	I _C = 1 A, V _{CE} = 2 V			1	V
C _{obo}	Output Capacitance	V _{CB} = 10 V, I _E = 0, f = 1.0 MHz			30	pF
f _T	Transition Frequency	I _C = 100 mA, V _{CE} = 5 V, f = 100 MHz		75		MHz

Note:

4. Pulse test: pulse width \leq 300 μ s, duty cycle \leq 2.0%

Typical Performance Characteristics

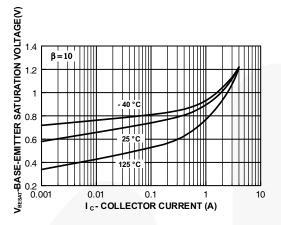


Figure 1. Base-Emitter Saturation Voltage vs. Collector Current

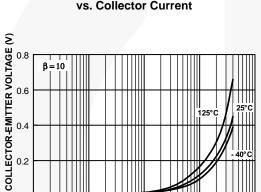


Figure 3. Collector-Emitter Saturation Voltage vs. Collector Current

I_c- COLLECTOR CURRENT (A)

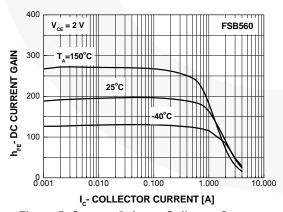


Figure 5. Current Gain vs. Collector Current

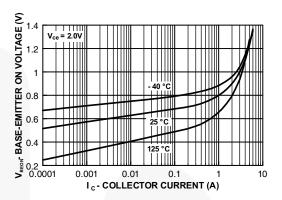


Figure 2. Base-Emitter On Voltage vs. Collector Current

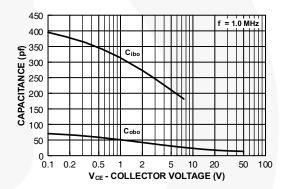


Figure 4. Input / Output Capacitance vs. Reverse Bias Voltage

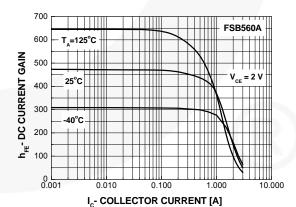


Figure 6. Current Gain vs. Collector Current

0.001

Physical Dimensions 0.95 2.92±0.12 — A 3 В 1.40 1.40±0.12 2.20 2 (0.29)--1.00◆ 0.20M A B 0.95 -1.90 -1.90 LAND PATTERN RECOMMENDATION SEE DETAIL A--1.12 MAX 0.10 (0.94)○ 0.10 C C 2.51 ± 0.20 GAGE PLANE NOTES: UNLESS OTHERWISE SPECIFIED 0.20 NO JEDEC REFERENCE AS OF AUGUST 2003 ALL DIMENSIONS ARE IN MILLIMETERS. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH AND TIE BAR EXTRUSIONS. DIMENSIONING AND TOLERANCING PER ASME Y14.5M — 1994. 0.43 0.33 SEATING PLANE (0.56)DETAIL A SCALE: 50:1 MA03BREVB

Figure 7. MOLDED PACKAGE, SUPERSOT, 3-LEAD





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Contact Us:

> Address:

401 Building No.5, JiuGe Business Center, Lane 2301, Yishan Rd Minhang District, Shanghai , China

> Sales:

Direct +86 (21) 6401-6692

Email amall@ameya360.com

QQ 800077892

Skype ameyasales1 ameyasales2

Customer Service :

Email service@ameya360.com

Partnership :

Tel +86 (21) 64016692-8333

Email mkt@ameya360.com